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**APPLICATION  
FOR  
UNITED STATES  
LETTERS PATENT**

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**FOR:                      VOLTAGE GENERATING APPARATUS  
INCLUDING RAPID AMPLIFIER AND SLOW  
AMPLIFIER**

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VOLTAGE GENERATING APPARATUS  
INCLUDING RAPID AMPLIFIER AND SLOW AMPLIFIER

DESCRIPTION OF THE INVENTION

5       Field of the Invention

          The present invention relates to a voltage generating apparatus for driving a capacitive load, and for example, to a gradation voltage generating apparatus used in an apparatus for driving a liquid crystal display (LCD) panel.

10       Description of the Related Art

          Generally, an apparatus for driving an LCD panel is constructed by a gradation voltage generating circuit as a power supply voltage generating circuit for generating gradation voltages and decoders for selecting two of the gradation voltages and applying the two gradation voltages to the LCD panel.

          In a first prior art LCD driving apparatus (see: Fig. 5 of JP-A-2000-20147), a gradation voltage generating circuit is constructed by a series of resistors and  
20   voltage-follower-type amplifiers for performing impedance transformation upon voltages at nodes of the resistors, and capacitors each connected to the voltage-follower-type amplifiers. Each of the voltage-follower-type amplifiers is a slow discharging amplifier or a slow charging amplifier with  
25   a single end type output circuit. This will be explained later in detail.

          In the above-described first prior art LCD driving apparatus, however, since the transient response is very low due to the single end type output circuit, the above-mentioned  
30   capacitors are externally provided to suppress the fluctuation of the transient response. This results in increasing the apparatus in size and cost.

          In a second prior art LCD driving apparatus (see:

Fig. 3 of JP-A-10-232383 and Fig. 7 of JP-A-2000-20147), a gradation voltage generating circuit is constructed by push-pull type amplifiers each including a slow discharging amplifier with a single end output circuit and a slow charging amplifier with a single end output circuit instead of the voltage-follower-type amplifiers of the first prior art LCD driving apparatus each with a single end output circuit. This also will be explained later in detail.

In the above-described second prior art LCD driving apparatus, however, since each of the discharging and charging amplifiers forming one push-pull type amplifier is of a slow type, the transient response is still low, which would invite flicker.

#### SUMMARY OF THE INVENTION

It is an object of the present invention to provide a voltage generating apparatus such as a gradation voltage generating circuit in an LCD driving apparatus having rapid transient response characteristics.

According to the present invention, in a voltage generating apparatus, a slow or rapid discharging amplifier is connected between an input terminal and an output terminal, and a rapid or slow charging amplifier is connected between the input terminal and the output terminal. An offset voltage generating element is connected between the input terminal and one of the slow or rapid discharging amplifier and the rapid or slow charging amplifier, so that an input voltage applied to the slow or rapid discharging amplifier is higher than an input voltage applied to the rapid or slow-charging amplifier. Thus, the transient response speed can be increased due to the presence of the rapid discharging amplifier or the rapid charging amplifier.

## BRIEF DESCRIPTION OF THE DRAWINGS

The present invention will be more clearly understood from the description set forth below, as compared with the prior art, with reference to the accompanying  
5 drawings, wherein:

Fig. 1 is a circuit diagram illustrating a first prior art LCD driving apparatus;

Fig. 2A is a circuit diagram of the slow discharging amplifier as the voltage-follower-type amplifier of Fig. 1;

10 Fig. 2B is a circuit diagram of the slow charging amplifier as the voltage-follower-type amplifier of Fig. 1;

Fig. 3 is a table for showing examples of the voltages at the common electrode and the segment element of Fig. 1;

15 Fig. 4 is a circuit diagram including the slow discharging amplifier of Fig. 2A;

Fig. 5 is a graph showing the voltage-to-current characteristics of the slow discharging amplifier of Fig. 4;

Fig. 6 is a timing diagram for explaining the operation of the slow discharging amplifier of Fig. 4;

20 Fig. 7 is a circuit diagram including the slow charging amplifier of Fig. 2B;

Fig. 8 is a graph showing the voltage-to-current characteristics of the slow charging amplifier of Fig. 7;

25 Fig. 9 is timing diagram for explaining the operation of the slow charging amplifier of Fig. 7;

Fig. 10 is a circuit diagram illustrating a second prior art LCD driving apparatus;

Fig. 11 is a circuit diagram of the push-pull type amplifier of Fig. 10;

30 Fig. 12 is a circuit diagram including the push-pull type amplifier of Fig. 11;

Fig. 13 is a graph showing the voltage-to-current characteristics of the push-pull type amplifier of Fig. 12;

Fig. 14 is a timing diagram for explaining the operation of the push-pull type amplifier of Fig. 12;

Fig. 15 is a circuit diagram illustrating a first embodiment of the LCD driving apparatus according to the  
5 present invention;

Fig. 16 is a circuit diagram of the push-pull type amplifier of Fig. 15;

Fig. 17 is a circuit diagram including the push-pull type amplifier of Fig. 16;

10 Fig. 18 is a graph showing the voltage-to-current characteristics of the push-pull type amplifier of Fig. 17;

Fig. 19 is a timing diagram for explaining the operation of the push-pull type amplifier of Fig. 17;

Fig. 20 is a circuit diagram illustrating a second  
15 embodiment of the LCD driving apparatus according to the present invention;

Fig. 21 is a circuit diagram of the push-pull type amplifier of Fig. 20;

Fig. 22 is a circuit diagram including the push-pull type  
20 amplifier of Fig. 21;

Fig. 23 is a graph showing the voltage-to-current characteristics of the push-pull type amplifier of Fig. 22;

Fig. 24 is a timing diagram for explaining the operation of the push-pull type amplifier of Fig. 22;

25 Fig. 25 is a timing diagram showing for explaining a modification of the operation of the push-pull type amplifier of Fig. 15;

Fig. 26 is a circuit diagram illustrating a third  
30 embodiment of the LCD driving apparatus according to the present invention;

Fig. 27 is a circuit diagram of the push-pull type amplifier of Fig. 26;

Fig. 28 is a circuit diagram including the push-pull type

amplifier of Fig. 27;

Fig. 29 is a graph showing the voltage-to-current characteristics of the push-pull type amplifier of Fig. 28;

Fig. 30 is a timing diagram for explaining the operation  
5 of the push-pull type amplifier of Fig. 28;

Fig. 31 is a timing diagram showing for explaining a modification of the operation of the push-pull type amplifier of Fig. 24;

Fig. 32 is a circuit diagram illustrating a third  
10 embodiment of the LCD driving apparatus according to the present invention;

Fig. 33 is a circuit diagram of the push-pull type amplifier of Fig. 32;

Fig. 34 is a circuit diagram including the push-pull type  
15 amplifier of Fig. 33;

Fig. 35 is a graph showing the voltage-to-current characteristics of the push-pull type amplifier of Fig. 34;

Fig. 36 is a timing diagram for explaining the operation of the push-pull type amplifier of Fig. 34;

Fig. 37 is a circuit diagram illustrating a modification  
20 of the push-pull amplifier of Fig. 27;

Fig. 38 is a circuit diagram illustrating a modification of the push-pull amplifier of Fig. 33;

Fig. 39 is a timing diagram showing the control signal  
25 and its inverted signal of Figs. 37 and 38;

Fig. 40 is a circuit diagram illustrating a modification of the push-pull amplifier of Fig. 28;

Fig. 41 is a circuit diagram illustrating a modification of the push-pull amplifier of Fig. 34; and

Fig. 42 is a timing diagram showing the control signals  
30 of Figs. 40 and 41.

#### DESCRIPTION OF THE PREFERRED EMBODIMENTS

Before the description of the preferred embodiments, prior art LCD driving apparatuses will be explained with reference to Figs. 1, 2A, 2B, 3, 4, 5, 6, 7, 8, 9, 10, 11, 12, 13 and 14.

5 In Fig. 1, which illustrates a first prior art LCD driving apparatus (see: Fig. 5 of JP-A-2000-20147), a gradation voltage generating circuit 101 generates gradation voltages VLCD, VLC1, VLC2, VLC3, VLC4 and GND, and transmits the gradation voltages to decoders 102 and 103. Note that the  
10 gradation voltage VLCD is generally much higher than a power supply voltage  $V_{DD}$ . For example, the gradation voltage VLCD can be generated by using a DC/DC converter.

The decoder 102 selects one of the gradation voltages VLCD, VLC1, VLC4 and GND in accordance with a frame  
15 polarity signal FRAM having a positive polarity FRAM+ and a negative polarity FRAM- and a vertical synchronization signal VSYNC, so that the selected gradation voltage is applied to a common electrode COM of a liquid crystal panel 104.

On the other hand, the decoder 103 selects one of  
20 the gradation voltages VLCD, VLC1, VLC2, VLC3, VLC4 and GND in accordance with the frame signal FRAM and a corresponding gradation data DT, so that the selected gradation voltage is applied to a segment electrode SEG of the liquid crystal panel 104. Note that there are generally a plurality of segment  
25 electrodes in the liquid crystal panel 104; however, in order to simplify the description, only one segment is illustrated.

The gradation voltage generating circuit 101 is constructed by a series of resistors R1, R2, R3, R4 and R5 serving as a voltage divider for dividing a voltage between  
30 VLCD and GND, voltage-follower-type amplifiers 1011, 1012, 1013 and 1014 for impedance transformation connected to nodes N1, N2, N3 and N4, respectively, of the resistors R1, R2, R3, R4 and R5, and capacitors C1, C2, C3, C4 and C5.

Each of the voltage-follower-type amplifiers 1011, 1012, 1013 and 1014 is constructed by a slow discharging amplifier as illustrated in Fig. 2A or a slow charging amplifier as illustrated in Fig. 2B in accordance with the driving method for the liquid crystal panel 104. For example, each of the voltage-follower-type amplifiers 1011 and 1013 is constructed by the slow discharging amplifier as illustrated in Fig. 2A, and each of the voltage-follower-type amplifiers 1012 and 1014 is constructed by the slow charging amplifier as illustrated in Fig. 2B.

In more detail, as illustrated in Fig. 2A, the slow discharging amplifier is constructed by a differential amplifier formed by a current source 201, P-channel MOS transistors 202 and 203, N-channel MOS transistors 204 and 205, a single end output circuit formed by a current source 206 and an N-channel MOS transistor 207, and a capacitor 208. In this case, the voltage at the node N1(N3) is applied to the gate of the transistor 203. On the other hand, the voltage VLC1 (VLC3) is negatively fed back to the gate of the MOS transistor 202. Note that if the voltage VLC1 (VLC3) is fed back to the gate of the MOS transistor 202 without the capacitor 208, oscillation may occur. Since the capacitor 208 serves as a phase compensating element, the amplifier of Fig. 2A is of a slow type for avoiding the above-mentioned oscillation.

Similarly, as illustrated in Fig. 2B, the slow charging amplifier is constructed by a differential amplifier formed by a current source 211, N-channel MOS transistors 212 and 203, P-channel MOS transistors 214 and 215, a single end output circuit formed by a current source 216 and a P-channel MOS transistor 217, and a capacitor 218. In this case, the voltage at the node N2 (N4) is applied to the gate of the transistor 213. On the other hand, the voltage VLC2 (VLC4) is negatively fed back to the gate of the MOS transistor 212. Note



that if the voltage VLC2 (VLC4) is fed back to the gate of the MOS transistor 202 without the capacitor 218, oscillation may occur. Since the capacitor 218 serves as a phase compensating element, the amplifier of Fig. 2B is of a slow type for avoiding the above-mentioned oscillation.

Each of the voltage-follower-type amplifiers 1011, 1012, 1013 and 1014 has a single-end type output circuit, not a push-pull type output circuit, so that no large penetration current flows therethrough, since a current flowing through the single-end type output circuit is limited by the current source 206 or 216.

In Fig. 3, which shows examples of the voltages at the common electrode COM and the segment element SEG of the liquid crystal panel 104, in a selected mode, although the difference in voltage between the common electrode COM and the segment electrode SEG is the same (for example, VLCD - GND), its polarity is switched by the frame polarity signal FRAM (FRAM+, FRAM-). On the other hand, in a non-selected mode, although the difference in voltage between the common electrode COM and the segment electrode SEG is the same (VMIN), its polarity is switched by the frame polarity signal FRAM (FRAM+, FRAM-). Thus, the deterioration of liquid crystal of the liquid crystal panel 104 can be suppressed.

The operation of the slow discharging amplifier of Fig. 2A will be explained next with reference to Figs. 4 and 5. In Fig. 4, the slow discharging amplifier of Fig. 2A is connected by the decoder 102 to the liquid crystal panel 104 so that the voltage VCOM at the common electrode COM is  $V_{COM} = V_{IN}$  while the voltage VSEG at the segment electrode SEG receives a voltage VL or VH via the decoder 103. In this case, the voltage  $(V_{COM} - V_{IN})$ -to-current I characteristics of the slow discharging amplifier of Fig. 4 are shown in Fig. 5. In Fig. 5, if  $V_{COM} > V_{IN}$ , the current I is relatively large due to

the turning-ON of the transistor 207. On the other hand, if  $V_{COM} \leq V_{IN}$ , the current  $I$  is limited by the current source 206 while the transistor 207 is turned OFF.

Next, the transient characteristics of the voltage  
5  $V_{COM}$  of Fig. 4 are explained with reference to Fig. 6.

First, at time  $t_1$ , when the voltage  $V_{SEG}$  is increased by the decoder 103 from  $V_L$  to  $V_H$ , the voltage  $V_{COM}$  is also increased by the capacitive coupling. In this case, the slow discharging amplifier is operated, i.e., the  
10 transistor 207 is turned ON to increase the backward current  $I$ , so that the voltage  $V_{COM}$  slowly recovers its original level  $V_{IN}$  with a time  $\tau_1$ . In this case, a small undershoot as indicated  $X_1$  is generated.

Next, at time  $t_2$ , when the voltage  $V_{SEG}$  is decreased  
15 by the decoder 103 from  $V_H$  to  $V_L$ , the voltage  $V_{COM}$  is also decreased by the capacitive coupling. In this case, the slow discharging amplifier is operated, i.e., the transistor 207 is turned OFF, so that the voltage  $V_{COM}$  very slowly recovers its original level  $V_{IN}$  with a time  $\tau_2$  which depends the  
20 current value of the current source 206. Since the current value of the current source 206 is limited, as shown in Fig. 6, the time  $\tau_2$  is larger than the time  $\tau_1$ . Therefore, no substantial overshoot as indicated by  $X_2$  is generated.

The operation of the slow charging amplifier of Fig.  
25 2B will be explained next with reference to Figs. 7 and 8. In Fig. 7, the slow charging amplifier of Fig. 2B is connected by the decoder 102 to the liquid crystal panel 104 so that the voltage  $V_{COM}$  at the common electrode COM is  $V_{COM} = V_{IN}$  while the voltage  $V_{SEG}$  at the segment electrode SEG receives a  
30 voltage  $V_L$  or  $V_H$  via the decoder 103. In this case, the voltage  $(V_{COM} - V_{IN})$ -to-current  $I$  characteristics of the slow charging amplifier of Fig. 7 are shown in Fig. 8. In Fig. 8, if  $V_{COM} < V_{IN}$ , the current  $I$  is relatively large due to the turning-ON

of the transistor 217. On the other hand, if  $V_{COM} \geq V_{IN}$ , the current  $I$  is limited by the current source 216 while the transistor 217 is turned OFF.

Next, the transient characteristics of the voltage  
5  $V_{COM}$  of Fig. 7 are explained with reference to Fig. 9.

First, at time  $t_1$ , when the voltage  $V_{SEG}$  is increased by the decoder 103 from  $V_L$  to  $V_H$ , the voltage  $V_{COM}$  is also increased by the capacitive coupling. In this case, the slow charging amplifier is operated, i.e., the transistor  
10 217 is turned OFF, so that the voltage  $V_{COM}$  very slowly recovers its original level  $V_{IN}$  with a time  $\tau_2'$  using the current source 216. In this case, no substantial undershoot as indicated by  $X_2'$  is generated.

Next, at time  $t_2$ , when the voltage  $V_{SEG}$  is decreased  
15 by the decoder 103 from  $V_H$  to  $V_L$ , the voltage  $V_{COM}$  is also decreased by the capacitive coupling. In this case, the slow charging amplifier is operated, i.e., the transistor 217 is turned ON to increase the forward current  $I$ , so that the voltage  $V_{COM}$  slowly recovers its original level  $V_{IN}$  with a time  
20  $\tau_1'$ . IN this case, a small overshoot as indicated by  $X_1'$  is generated.

The time  $\tau_2'$  depends the current value of the current source 216. Since the current value of the current source 216 is limited, as shown in Fig. 9, the time  $\tau_2'$  is  
25 larger than the time  $\tau_1'$ .

In order to suppress the fluctuation of the times  $\tau_2$  and  $\tau_2'$ , the capacitors  $C_0$ ,  $C_1$ ,  $C_2$ ,  $C_3$  and  $C_4$  are externally provided in the LCD driving apparatus of Fig. 1, since each of the capacitors  $C_0$ ,  $C_1$ ,  $C_2$ ,  $C_3$  and  $C_4$  has a  
30 relatively large capacitance. In this case, however, the LCD driving apparatus of Fig. 1 is increased in size and cost.

In Fig. 10, which illustrates a second prior art LCD driving apparatus (see: Fig. 3 of JP-A-10-232383 and Fig. 7

of JP-A-2000-20147), the gradation voltage generating circuit 101 of Fig. 1 is replaced by a gradation voltage generating circuit 301.

In the gradation voltage generating circuit 301, resistors  $r1$ ,  $r2$ ,  $r3$  and  $r4$  for generating offset voltages are inserted in series with the resistors  $R1$ ,  $R2$ ,  $R3$ ,  $R4$  and  $R5$  of Fig. 1. Also, the single-end-type voltage-follower-type amplifiers 1011, 1012, 1013 and 1014 of Fig. 1 are replaced by push-pull type amplifiers 3011, 3012, 3013 and 3014, respectively. Each of the push-pull type amplifiers 3011, 3012, 3013 and 3014 is constructed by a slow discharging amplifier such as 3011N and a slow charging amplifier 3011P as illustrated in Fig. 11. Note that the resistance values of the resistors  $r1$ ,  $r2$ ,  $r3$  and  $r4$  are smaller than those of the resistors  $R1$ ,  $R2$ ,  $R3$ ,  $R4$  and  $R5$ , and therefore, an offset voltage  $\Delta V$  is generated between the nodes  $N1$  and  $N1'$ , between the nodes  $N2$  and  $N2'$ , between the nodes  $N3$  and  $N3'$ , and between the nodes  $N4$  and  $N4'$ .

In Fig. 10, the externally-provided capacitors  $C0$ ,  $C1$ ,  $C2$ ,  $C3$  and  $C4$  of Fig. 1 are not provided, which would decrease the LCD driving apparatus of Fig. 8 in size and cost.

In Fig. 11, the slow discharging amplifier such as 3011N has the same configuration as the slow discharging amplifier of Fig. 2A, and the slow charging amplifier such as 3011P has the same configuration as the slow charging amplifier of Fig. 2B. That is, the two single end type amplifiers are combined into a push-pull type amplifier.

The operation of the push-pull type amplifier of Fig. 11 will be explained next with reference to Figs. 12 and 13. In Fig. 12, the push-pull type amplifier of Fig. 11 is connected by the decoder 102 to the liquid crystal panel 104 so that the voltage  $V_{COM}$  at the common electrode COM is  $V_{COM} = V_{IN}$  while the voltage  $V_{SEG}$  at the segment electrode SEG

receives a voltage  $V_L$  or  $V_H$  via the decoder 103. In this case, the voltage  $(V_{COM} - V_{IN})$ -to-current  $I$  characteristics of the push-pull type amplifier of Fig. 12 are shown in Fig. 13. In Fig. 13, if  $V_{COM} > V_{IN}$ , the current  $I$  is relatively large due to the turning-ON of the transistor 207 of Fig. 11. On the other hand, if  $V_{COM} < V_{IN} - \Delta V$  where  $\Delta V$  is the offset voltage, the current  $I$  is relatively large due to the turning-ON of the transistor 217.

Next, the transient characteristics of the voltage  $V_{COM}$  of Fig. 12 are explained with reference to Fig. 14.

First, at time  $t_1$ , when the voltage  $V_{SEG}$  is increased by the decoder 103 from  $V_L$  to  $V_H$ , the voltage  $V_{COM}$  is also increased by the capacitive coupling. In this case, the slow discharging amplifier 3011N is operated, i.e., the transistor 207 is turned ON to increase the backward current  $I$ , so that the voltage  $V_{COM}$  slowly recovers its original level  $V_{IN}$  with a time  $\tau_1$ . In this case, a small undershoot as indicated by  $X_1$  is generated.

Next, at time  $t_2$ , when the voltage  $V_{SEG}$  is decreased by the decoder 103 from  $V_H$  to  $V_L$ , the voltage  $V_{COM}$  is also decreased by the capacitive coupling. In this case, the slow charging 3011P amplifier is operated, i.e., the transistor 217 is turned ON to increase the forward current  $I$ , so that the voltage  $V_{COM}$  slowly recovers its original level  $V_{IN}$  with a time  $\tau_1'$ . In this case, a small overshoot as indicated by  $X_1'$  is generated.

Note that, in Fig. 14, if the offset voltage  $\Delta V$  is very small, no consideration can be given to the offset voltage  $\Delta V$ . However, the offset voltage  $\Delta V$  is indispensable in order to prevent the transistors 207 and 217 from being simultaneously turned ON to create a short-circuited state where an ON-ON current flows.

In the LCD driving apparatus of Fig. 10, however,

the discharging amplifier and the charging amplifier forming one push-pull type amplifier are both of a slow type including the capacitors 208 and 218 of Fig. 11, so that the transient response as shown in Fig. 14 is still slow which would invite  
 5 flicker.

In Fig. 15, which illustrates a first embodiment of the LCD driving apparatus according to the present invention, the gradation voltage generating circuit 301 of Fig. 10 is replaced by a gradation voltage generating circuit 1.

10 In the gradation voltage generating circuit 1, the push-pull type amplifiers 3011, 3012, 3013 and 3014 of Fig. 10 are replaced by push-pull type amplifiers 11, 12, 13 and 14, respectively. Each of the push-pull type amplifiers 11, 12, 13 and 14 is constructed by a slow discharging amplifier  
 15 such as 11N and a rapid charging amplifier 11p as illustrated in Fig. 16. Note that a resistor r is used for suppressing an ON-ON current when the transistors 207 and 217 of Fig. 16 are both turned ON.

In Fig. 16, the slow discharging amplifier such as  
 20 11N has the same configuration as the slow discharging amplifier of Fig. 11, and the rapid charging amplifier such as 11P has the same configuration as the slow charging amplifier of Fig. 11 except that the capacitor 218 is not provided.

25 The operation of the push-pull type amplifier of Fig. 16 will be explained next with reference to Figs. 17 and 18. In Fig. 17, the push-pull type amplifier of Fig. 16 is connected by the decoder 102 to the liquid crystal panel 104 so that the voltage VCOM at the common electrode COM is  $V_{COM} = V_{IN}$  while the voltage VSEG at the segment electrode SEG  
 30 receives a voltage VL or VH via the decoder 103. In this case, the voltage  $(V_{COM} - V_{IN})$ -to-current I characteristics of the push-pull type amplifier of Fig. 17 are shown in Fig. 18. In

Fig. 13, if  $V_{COM} > V_{IN}$ , the current  $I$  is relatively large due to the turning-ON of the transistor 207 of Fig. 16. On the other hand, if  $V_{COM} < V_{IN} - \Delta V$  where  $\Delta V$  is the offset voltage, the current  $I$  is very large due to the turning-ON of the transistor 217, since the capacitor 218 is not provided.

Note that the rapid charging amplifier 11p may easily oscillate; in this case, however, since the rapid charging amplifier 11p is connected to the slow discharging amplifier 11N which may hardly oscillate, the rapid charging amplifier 11p hardly oscillates.

Next, the transient characteristics of the voltage  $V_{COM}$  of Fig. 17 are explained with reference to Fig. 19.

First, at time  $t_1$ , when the voltage  $V_{SEG}$  is increased by the decoder 103 from  $V_L$  to  $V_H$ , the voltage  $V_{COM}$  is also increased by the capacitive coupling. In this case, the slow discharging amplifier 11N is operated, i.e., the transistor 207 is turned ON to increase the backward current  $I$ , so that the voltage  $V_{COM}$  slowly recovers its original level  $V_{IN}$  with a time  $\tau_1$ . In this case, a small undershoot as indicated by  $X_1$  is generated.

Next, at time  $t_2$ , when the voltage  $V_{SEG}$  is decreased by the decoder 103 from  $V_H$  to  $V_L$ , the voltage  $V_{COM}$  is also decreased by the capacitive coupling. In this case, the rapid charging amplifier 11p is operated, i.e., the transistor 217 is turned ON to increase the forward current  $I$ , so that the voltage  $V_{COM}$  rapidly recovers its original level  $V_{IN}$  with a time  $\tau_0'$ . In this case, a large overshoot may be generated; however, no substantial overshoot as indicated by  $X_0'$  is generated due to the presence of the offset voltage  $\Delta V$ .

Thus, in the LCD driving apparatus of Fig. 15, the charging amplifier forming one push-pull type amplifier is of a rapid type, the transient response as shown in Fig. 19 is rapid which would invite no flicker.

In Fig. 20, which illustrates a second embodiment of the LCD driving apparatus according to the present invention, the gradation voltage generating circuit 301 of Fig. 10 is replaced by a gradation voltage generating circuit 2.

5 In the gradation voltage generating circuit 2, the push-pull type amplifiers 3011, 3012, 3013 and 3014 of Fig. 10 are replaced by push-pull type amplifiers 21, 22, 23 and 24, respectively. Each of the push-pull type amplifiers 21, 22, 23 and 24 is constructed by a rapid discharging amplifier  
10 such as 21n and a slow charging amplifier 21P as illustrated in Fig. 21. Note that a resistor  $r$  is used for suppressing an ON-ON current when the transistors 207 and 217 of Fig. 21 are both turned ON.

In Fig. 21, the rapid discharging amplifier such as  
15 21n has the same configuration as the slow discharging amplifier of Fig. 11 except that the capacitor 208 is not provided, and the slow charging amplifier such as 21P has the same configuration as the slow charging amplifier of Fig. 11.

The operation of the push-pull type amplifier of Fig. 21 will be explained next with reference to Figs. 22 and 23.  
20 In Fig. 22, the push-pull type amplifier of Fig. 21 is connected by the decoder 102 to the liquid crystal panel 104 so that the voltage  $V_{COM}$  at the common electrode COM is  $V_{COM} = V_{IN}$  while the voltage  $V_{SEG}$  at the segment electrode SEG  
25 receives a voltage  $V_L$  or  $V_H$  via the decoder 103. In this case, the voltage  $(V_{COM} - V_{IN})$ -to-current  $I$  characteristics of the push-pull type amplifier of Fig. 22 are shown in Fig. 23. In Fig. 23, if  $V_{COM} > V_{IN}$ , the current  $I$  is very large due to the turning-ON of the transistor 207 of Fig. 21, since the  
30 capacitor 208 is not provided. On the other hand, if  $V_{COM} < V_{IN} - \Delta V$  where  $\Delta V$  is the offset voltage, the current  $I$  is relatively large due to the turning-ON of the transistor 217.

Note that the rapid discharging amplifier 21n may



easily oscillate; in this case, however, since the rapid discharging amplifier 21n is connected to the slow charging amplifier 21p which may hardly oscillate, the rapid discharging amplifier 21n hardly oscillates.

5           Next, the transient characteristics of the voltage VCOM of Fig. 22 are explained with reference to Fig. 24.

First, at time  $t_1$ , when the voltage VSEG is increased by the decoder 103 from VL to VH, the voltage VCOM is also increased by the capacitive coupling. In this case, 10 the rapid discharging amplifier 21n is operated, i.e., the transistor 207 is turned ON to increase the backward current I, so that the voltage VCOM rapidly recovers its original level VIN with a time  $\tau_0$  ( $< \tau_1$ ). In this case, a large undershoot as indicated by X0 is generated.

15           Next, at time  $t_2$ , when the voltage VSEG is decreased by the decoder 103 from VH to VL, the voltage VCOM is also decreased by the capacitive coupling. In this case, the slow charging 21p amplifier is operated, i.e., the transistor 217 is turned ON to increase the forward current I, so that the 20 voltage VCOM slowly recovers its original level VIN with a time  $\tau_1$ . In this case, an overshoot may be generated; however, no substantial overshoot as indicated in X1' is generated due to the presence of the offset voltage.

Thus, in the LCD driving apparatus of Fig. 20, 25 discharging amplifier forming one push-pull type amplifier is of a rapid type, the transient response as shown in Fig. 24 is rapid which would invite no flicker.

In Fig. 19, when the offset voltage  $\Delta V$  is decreased, the transient response speed can be increased as shown in Fig. 30 25. In this case, however, since the turning-ON period  $T_d$  of the discharging transistor 207 of Fig. 16 is superimposed onto the turning-ON period  $T_c$  of the charging transistor 217 of Fig. 16, an ON-ON current may flow therethrough during a period  $\Delta$

T. Similarly, since the turning-ON period  $T_c'$  of the charging transistor 217 of Fig. 16 is superimposed onto the turning-ON period  $T_d'$  of the discharging transistor 207 of Fig. 16, an ON-ON current may flow therethrough during a period  $\Delta T'$ .

5 In Fig. 26, which illustrates a third embodiment of the LCD driving apparatus according to the present invention, the gradation voltage generating circuit 1 of Fig. 15 is replaced by a gradation voltage generating circuit 3.

10 In the gradation voltage generating circuit 3, resistors  $r1'$ ,  $r2'$ ,  $r3'$  and  $r4'$  for other offset voltages are inserted in series with the resistors  $R1$ ,  $R2$ ,  $R3$  and  $R4$  of Fig. 15. Also, the push-pull type amplifiers 11, 12, 13 and 14 of Fig. 15 are replaced by push-pull type amplifiers 31, 32, 33 and 34, respectively. Each of the push-pull type amplifiers  
15 31, 32, 33 and 34 further includes a rapid discharging amplifier such as 11n in addition to the slow discharging amplifier such as 11N and the rapid charging amplifier 11p as illustrated in Fig. 27.

20 In Fig. 27, the rapid discharging amplifier such as 11n has the same configuration as the slow discharging amplifier 11N except that the capacitor 208 is not provided.

The operation of the push-pull type amplifier of Fig. 27 will be explained next with reference to Figs. 28 and 29. In Fig. 28, the push-pull type amplifier of Fig. 27 is  
25 connected by the decoder 102 to the liquid crystal panel 104 so that the voltage  $V_{COM}$  at the common electrode COM is  $V_{COM} = V_{IN}$  while the voltage  $V_{SEG}$  at the segment electrode SEG receives a voltage  $V_L$  or  $V_H$  via the decoder 103. In this case, the voltage  $(V_{COM} - V_{IN})$ -to-current  $I$  characteristics of the  
30 push-pull type amplifier of Fig. 28 are shown in Fig. 29. In Fig. 29, if  $V_{COM} > V_{IN}$ , the current  $I$  is very large due to the turning-ON of the transistors 207 and 207' of Fig. 27. Also, if  $0 < V_{COM} - V_{IN} \leq \Delta V$ , the current  $I$  is relatively large

due to the turning-ON of the transistor 207 of Fig. 27. On the other hand, if  $V_{COM} < V_{IN} - \Delta V$ , the current  $I$  is very large due to the turning-ON of the transistor 217.

Note that the rapid amplifiers 11p and 11n may easily oscillate; in this case, however, since the rapid amplifiers 11p and 11n connected to the slow discharging amplifier 11N which may hardly oscillate, the rapid amplifiers 11p and 11n hardly oscillate.

Next, the transient characteristics of the voltage  $V_{COM}$  of Fig. 28 are explained with reference to Fig. 30.

First, at time  $t_1$ , when the voltage  $V_{SEG}$  is increased by the decoder 103 from  $V_L$  to  $V_H$ , the voltage  $V_{COM}$  is also increased by the capacitive coupling. In this case, the rapid discharging amplifier 11n and the slow discharging amplifier 11N are operated, i.e., the transistors 207 and 207' are turned ON to increase the backward current  $I$ , so that the voltage  $V_{COM}$  very rapidly recovers its original level  $V_{IN}$  with a time  $\tau_0$ . In this case, an undershoot as indicated by  $X_0$  is generated, however, afterward, the operation of the rapid discharging amplifier 11n is stopped, i.e., only the slow discharging amplifier 11N is operated. As a result, the undershoot as indicated by  $X_0$  is relatively small, so that the response speed is increased.

Next, at time  $t_2$ , when the voltage  $V_{SEG}$  is decreased by the decoder 103 from  $V_H$  to  $V_L$ , the voltage  $V_{COM}$  is also decreased by the capacitive coupling. In this case, the rapid charging amplifier 11p is operated, i.e., the transistor 217 is turned ON to increase the forward current  $I$ , so that the voltage  $V_{COM}$  rapidly recovers its original level  $V_{IN}$  with a time  $\tau_0'$ . In this case, a large overshoot may be generated; however, no substantial overshoot as indicated by  $X_0'$  is generated due to the presence of the offset voltage  $\Delta V$ .

Thus, in the LCD driving apparatus of Fig. 26, the

discharging amplifiers and the charging amplifier forming one push-pull type amplifier are substantially of a rapid type, even if the offset voltage  $\Delta V$  is large, the transient response as shown in Fig. 30 is rapid which would invite no flicker.

5 In Fig. 24, when the offset voltage  $\Delta V$  is decreased, the transient response speed can be increased as shown in Fig. 31. In this case, however, since the turning-ON period  $T_d$  of the discharging transistor 207 of Fig. 21 is superimposed onto the turning-ON period  $T_c$  of the charging transistor 217 of Fig. 16, an ON-ON current may flow therethrough during a period  $\Delta T$ . Similarly, since the turning-ON period  $T_c'$  of the charging transistor 217 of Fig. 21 is superimposed onto the turning-ON period  $T_d'$  of the discharging transistor 207 of Fig. 21, an ON-ON current may flow therethrough during a period  $\Delta T'$ .

15 In Fig. 32, which illustrates a fourth embodiment of the LCD driving apparatus according to the present invention, the gradation voltage generating circuit 2 of Fig. 20 is replaced by a gradation voltage generating circuit 4.

In the gradation voltage generating circuit 4, 20 resistors  $r1'$ ,  $r2'$ ,  $r3'$  and  $r4'$  for other offset voltages are inserted in series with the resistors  $R1$ ,  $R2$ ,  $R3$  and  $R4$  of Fig. 20. Also, the push-pull type amplifiers 21, 22, 23 and 24 of Fig. 20 are replaced by push-pull type amplifiers 41, 42, 43 and 44, respectively. Each of the push-pull type amplifiers 25 41, 42, 43 and 44 further includes a rapid charging amplifier such as 21p in addition to the rapid discharging amplifier such as 21n and the slow charging amplifier 21p as illustrated in Fig. 33.

30 In Fig. 33, the rapid charging amplifier such as 21p has the same configuration as the slow discharging amplifier 21N except that the capacitor 218 is not provided.

The operation of the push-pull type amplifier of Fig. 33 will be explained next with reference to Figs. 34 and 35.

In Fig. 34, the push-pull type amplifier of Fig. 27 is connected by the decoder 102 to the liquid crystal panel 104 so that the voltage  $V_{COM}$  at the common electrode COM is  $V_{COM} = V_{IN}$  while the voltage  $V_{SEG}$  at the segment electrode SEG receives a voltage  $V_L$  or  $V_H$  via the decoder 103. In this case, the voltage  $(V_{COM} - V_{IN})$ -to-current  $I$  characteristics of the push-pull type amplifier of Fig. 34 are shown in Fig. 35. In Fig. 35, if  $V_{COM} > V_{IN}$ , the current  $I$  is very large due to the turning-ON of the transistor 207 of Fig. 33. On the other hand, if  $-\Delta V < V_{COM} - V_{IN} \leq 0$ , the current  $I$  is relatively large due to the turning-ON of the transistor 217 of Fig. 33. Further, if  $V_{COM} \leq V_{IN} - \Delta V$ , the current  $I$  is very large due to the turning-ON of the transistors 217 and 217' of Fig. 33.

Note that the rapid amplifiers 21p and 21n may easily oscillate; in this case, however, since the rapid amplifiers 21p and 21n connected to the slow charging amplifier 21P which may hardly oscillate, the rapid amplifiers 21p and 21n hardly oscillate.

Next, the transient characteristics of the voltage  $V_{COM}$  of Fig. 34 are explained with reference to Fig. 36.

First, at time  $t_1$ , when the voltage  $V_{SEG}$  is increased by the decoder 103 from  $V_L$  to  $V_H$ , the voltage  $V_{COM}$  is also increased by the capacitive coupling. In this case, the rapid discharging amplifier 21n is operated, i.e., the transistor 207 is turned ON to increase the backward current  $I$ , so that the voltage  $V_{COM}$  very rapidly recovers its original level  $V_{IN}$  with a time  $\tau_0$ . In this case, an undershoot as indicated  $X_0$  is generated.

Next, at time  $t_2$ , when the voltage  $V_{SEG}$  is decreased by the decoder 103 from  $V_H$  to  $V_L$ , the voltage  $V_{COM}$  is also decreased by the capacitive coupling. In this case, the rapid charging amplifier 21p and the slow charging amplifier 21p are operated, i.e., the transistors 217 and 217' are turned ON

to increase the forward current  $I$ , so that the voltage  $V_{COM}$  very rapidly recovers its original level  $V_{IN}$  with a time  $\tau$  0'. In this case, a large overshoot may be generated; however, no substantial overshoot as indicated by  $X0'$  is generated, because afterward, the operation of the rapid charging amplifier 21p is stopped, i.e., only the slow changing amplifier 21P is operated.

Thus, in the LCD driving apparatus of Fig. 32, the discharging amplifier and the charging amplifiers forming one push-pull type amplifier are substantially of a rapid type, even if the offset voltage  $\Delta V$  is large, the transient response as shown in Fig. 36 is rapid which would invite no flicker.

In Fig. 37, which illustrates a modification of the push-pull amplifier of Fig. 27, the rapid discharging amplifier 11n and the slow discharging amplifier 11N of Fig. 27 are combined into one discharging amplifier 11 (n, N). That is, three operational amplifiers are provided in Fig. 27, while two operational amplifiers are provided in Fig. 37. As a result, the push-pull amplifier of Fig. 37 is smaller in size than that of Fig. 27.

In Fig. 37, an N-channel MOS transistor 371 and switches 372 and 373 are added to the slow discharging amplifier 11N of Fig. 27, thus realizing the discharging amplifier 11(n, N). When  $CNT = "0"$  (low), the switches 372 and 373 are turned ON and OFF, respectively, so that the transistor 371 is turned OFF and the capacitor 208 is active, and thus, the discharging amplifier 11(n, N) serves as the rapid discharging amplifier 11n of Fig. 27. On the other hand, when  $CNT = "1"$  (low), the switches 372 and 373 are turned OFF and ON, respectively, so that the transistor 371 is turned ON and the capacitor 208 is inactive, and thus, the discharging amplifier 11(n, N) serves as the slow discharging amplifier 11N of Fig. 27. In this case, the turning-ON transistor 371

serves as an offset voltage generator, and therefore, the resistors  $r1'$ ,  $r2'$ ,  $r3'$  and  $r4'$  of Fig. 26 are unnecessary.

In Fig. 38, which illustrates a modification of the push-pull amplifier of Fig. 33, the rapid charging amplifier 21p and the slow charging amplifier 21P of Fig. 33 are combined into one charging amplifier 21 (p, P). That is, three operational amplifiers are provided in Fig. 33, while two operational amplifiers are provided in Fig. 38. As a result, the push-pull amplifier of Fig. 38 is smaller in size than that of Fig. 33.

In Fig. 38, a P-channel MOS transistor 381 and switches 382 and 383 are added to the slow charging amplifier 21P of Fig. 33, thus realizing the charging amplifier 21(p, P). When CNT = "0"(low), the switches 382 and 383 are turned ON and OFF, respectively, so that the transistor 381 is turned OFF and the capacitor 218 is active, and thus, the charging amplifier 21(p, P) serves as the rapid charging amplifier 21p of Fig. 33. On the other hand, when CNT = "1"(low), the switches 382 and 383 are turned OFF and ON, respectively, so that the transistor 381 is turned ON and the capacitor 218 is inactive, and thus, the charging amplifier 21(p, P) serves as the slow charging amplifier 21P of Fig. 33. In this case, the turning-On transistor 381 serves as an offset voltage generator, and therefore, the resistors  $r1'$ ,  $r2'$ ,  $r3'$  and  $r4'$  of Fig. 32 are unnecessary.

The control signal CNT and its inverted signal of Figs. 37 and 38 are shown in Fig. 39. That is, when the data signal DT is changed, the control signal CNT and its inverted signal are changed for a predetermined time period, so that the discharging amplifier 11(n, N) of Fig. 37 or the charging amplifier 21(p, N) of Fig. 38 carries out a slow discharging or charging operation.

In Fig. 40, which illustrates a modification of the

push-pull amplifier of Fig. 28, switches 401, 402 and 403 controlled by control signals CNT1 and CNT2 are added to the push-pull amplifier of Fig. 28. That is, the three operational amplifiers are always activated in Fig. 28, while the

5 operational amplifiers are selected and activated in Fig. 40. As a result, the power consumption of the push-pull amplifier of Fig. 40 is smaller than that of the push-pull amplifier of Fig. 28.

10 In Fig. 40, when the control signal CNT1 and CNT2 are "0"(low) and "1"(high), respectively, the rapid amplifiers 11n and 11p are activated. On the other hand, when the control signals CNT1 and CNT2 are "1"(high) and "0"(low), respectively, the slow amplifier 11N is activated.

15 In Fig. 41, which illustrates a modification of the push-pull amplifier of Fig. 34, switches 411, 412 and 413 controlled by control signals CNT1 and CNT2 are added to the push-pull amplifier of Fig. 34. That is, the three operational amplifiers are always activated in Fig. 34, while the operational amplifiers are selected and activated in Fig. 41.

20 As a result, the power consumption of the push-pull amplifier of Fig. 41 is smaller than that of the push-pull amplifier of Fig. 34.

In Fig. 41, when the control signals CNT1 and CNT2 are "0"(low) and "1"(high), respectively, the rapid amplifiers 21n and 21p are activated. On the other hand, when the control signals CNT1 and CNT2 are "1"(high) and "0"(low), respectively, the slow amplifier 21P is activated.

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The control signals CNT1 and CNT2 of Figs. 40 and 41 are shown in Fig. 42. That is, when the data signal DT is changed, the control signals CNT1 and CNT2 are changed for a predetermined time period, so that the amplifiers 11p and 11n of Fig. 40 or the rapid amplifiers 21p and 21n of Fig. 41 carry out a rapid discharging or charging operation.

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The present invention can be applied to a voltage generating apparatus other than a gradation voltage generating circuit in an LCD apparatus.

As explained hereinabove, since at least one rapid  
5 amplifier is included in a push-pull type amplifier of a  
voltage generating apparatus, the transient response  
characteristics can be rapid. Also, since a slow amplifier is  
included in the push-pull type amplifier, the rapid amplifier  
hardly oscillates.